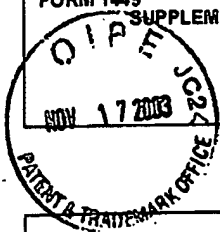


FORM 1449* INFORMATION DISCLOSURE STATEMENT IN AN APPLICATION (Use several sheets if necessary)	Docket Number: HSJ920030016US3	Application Number:
	Applicant: GILL et al.	
	Filing Date: 07/29/2003	Group Art Unit: unassigned

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A/H	July 1998	Takahashi, M., Maeda, T., Inage, K., Sakai, M., Morita, H., and Matsuzaki, M., "EDS Induced Pinned Layer Reversal in Spin-Valve GMR Heads," <i>IEEE TRANSACTIONS ON MAGNETICS</i> , Vol. 34, No. 4., July 1998.					
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EXAMINER	A. Heinz	DATE CONSIDERED	7/12/05
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form for next communication to the Applicant.			

FORM 1449* SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT IN AN APPLICATION (Use several sheets if necessary)	Docket Number:	Application Number:
	HSJ920030016US3	10/629,323
	Applicant: Gill <i>et al.</i>	
	Filing Date: 7/29/2003	Group Art Unit: 2651



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EXAMINER	<i>A. Heinz</i>	DATE CONSIDERED	<i>7/18/05</i>
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